

2SA1762

Silicon PNP epitaxial planer type

For low-frequency driver amplification

Complementary to 2SC4606

Features

- High collector to emitter voltage V_{CEO} .
- Optimum for the driver stage of a low-frequency and 25 to 30W output amplifier.

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-80	V
Collector to emitter voltage	V_{CEO}	-80	V
Emitter to base voltage	V_{EBO}	-5	V
Peak collector current	I_{CP}	-1	A
Collector current	I_C	-0.5	A
Collector power dissipation	P_C^*	1	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ~ +150	$^\circ\text{C}$

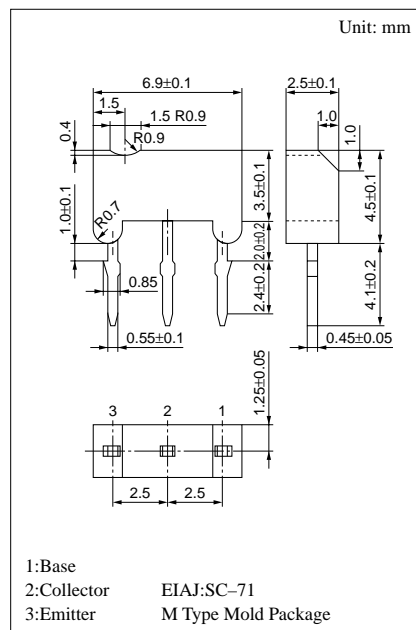
* Printed circuit board: Copper foil area of 1cm² or more, and the board thickness of 1.7mm for the collector portion

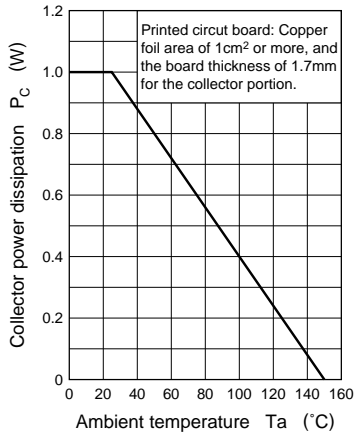
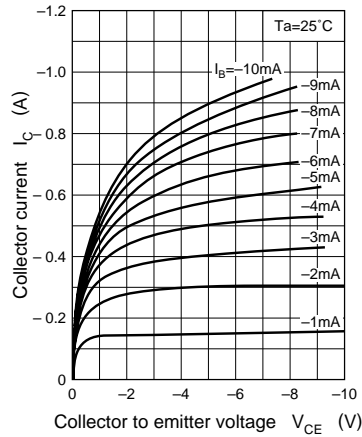
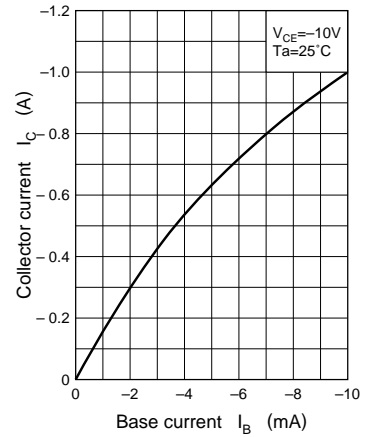
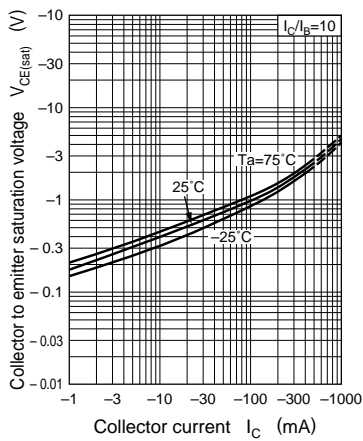
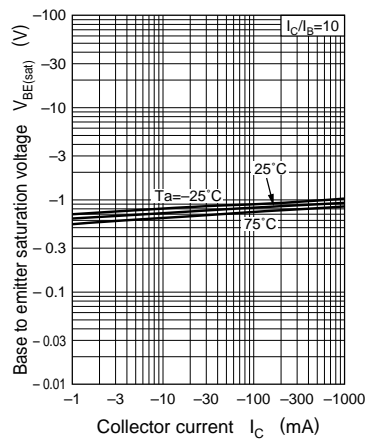
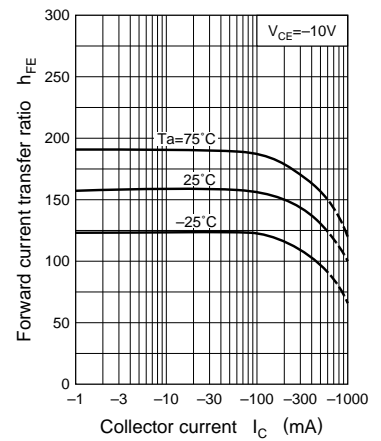
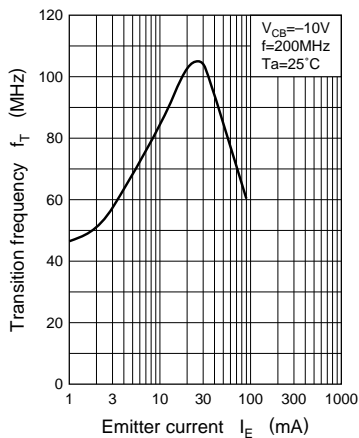
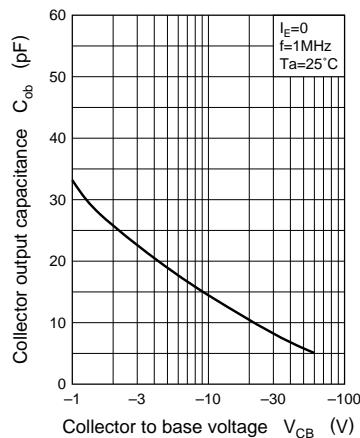
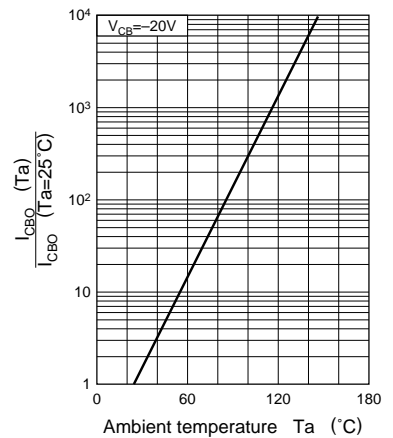
Electrical Characteristics ($T_a=25^\circ\text{C}$)

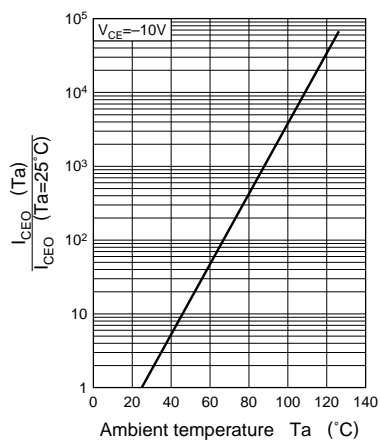
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -20\text{V}$, $I_E = 0$			-0.1	μA
Collector to base voltage	V_{CBO}	$I_C = -10\mu\text{A}$, $I_E = 0$	-80			V
Collector to emitter voltage	V_{CEO}	$I_C = -100\mu\text{A}$, $I_B = 0$	-80			V
Emitter to base voltage	V_{EBO}	$I_E = -10\mu\text{A}$, $I_C = 0$	-5			V
Forward current transfer ratio	h_{FE1}^*	$V_{CE} = -10\text{V}$, $I_C = -150\text{mA}$	130		330	
	h_{FE2}	$V_{CE} = -5\text{V}$, $I_C = -500\text{mA}$	50	100		
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -300\text{mA}$, $I_B = -30\text{mA}$		-0.2	-0.4	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = -300\text{mA}$, $I_B = -30\text{mA}$		-0.85	-1.2	V
Transition frequency	f_T	$V_{CB} = -10\text{V}$, $I_E = 50\text{mA}$, $f = 200\text{MHz}$		85		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{V}$, $I_E = 0$, $f = 1\text{MHz}$		11	20	pF

* h_{FE1} Rank classification

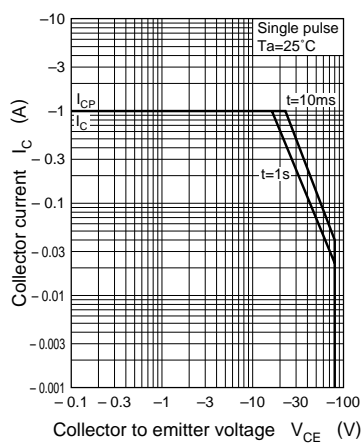
Rank	R	S
h_{FE1}	130 ~ 220	185 ~ 330



$P_C - T_a$  $I_C - V_{CE}$  $I_C - I_B$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $C_{ob} - V_{CB}$  $I_{CBO} - T_a$ 

$I_{CEO} - T_a$ 

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